TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT process)

## 2SA1300

# Strobe Flash Applications Medium Power Amplifier Applications

• High DC current gain and excellent hFE linearity

:  $h_{FE}$  (1) = 140~600 ( $V_{CE}$  = -1 V,  $I_{C}$  = -0.5 A)

: hFE (2) = 60 (min), 120 (typ.) (VCE = -1 V, IC = -4 A)

• Low saturation voltage:  $V_{CE (sat)} = -0.5 \text{ V (max)}$ 

(IC = -2 A, IB = -50 mA)

## **Maximum Ratings (Ta = 25°C)**

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		$V_{CBO}$	-20	V	
Collector-emitter voltage		V <sub>CES</sub>	-20	V	
		$V_{CEO}$	-10		
Emitter-base voltage		V <sub>EBO</sub>	-6	V	
Collector current	DC	I <sub>C</sub>	-2	А	
	Pulsed (Note 1)	I <sub>CP</sub>	-5		
Base current		I <sub>B</sub>	-0.2	Α	
Collector power dissipation		PC	750	mW	
Junction temperature		Tj	150	°C	
Storage temperature range		T <sub>stg</sub>	-55~150	°C	

Note 1: Pulse width = 10 ms (max), duty cycle = 30% (max)

# Unit: mm 5.1 MAX. 0.45 0.45 0.45 1. EMITTER 2. COLLECTOR 3. BASE JEDEC TO-92 JEITA SC-43 TOSHIBA 2-5F1B

Weight: 0.21 g (typ.)

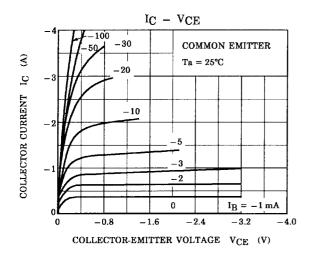
## **Electrical Characteristics (Ta = 25°C)**

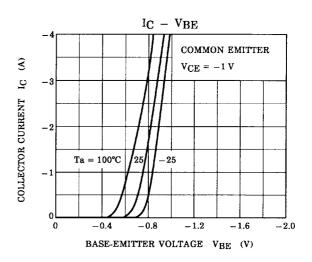
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	$V_{CB} = -20 \text{ V}, I_E = 0$	_	_	-0.1	μΑ
Emitter cut-off current	I <sub>EBO</sub>	$V_{EB} = -6 \text{ V}, I_{C} = 0$	_	_	-0.1	μΑ
Collector-emitter breakdown voltage	V (BR) CEO	$I_C = -10 \text{ mA}, I_B = 0$	-10	_	_	V
Emitter-base breakdown voltage	V (BR) EBO	$I_E = -1 \text{ mA}, I_C = 0$	-6	_	_	V
DC current gain	h <sub>FE (1)</sub> (Note 2)	V <sub>CE</sub> = -1 V, I <sub>C</sub> = -0.5 A	140	_	600	
	h <sub>FE</sub> (2)	V <sub>CE</sub> = -1 V, I <sub>C</sub> = -4 A	60	120	_	
Collector-emitter saturation voltage	V <sub>CE</sub> (sat)	$I_C = -2 \text{ A}, I_B = -50 \text{ mA}$	_	-0.2	-0.5	V
Base-emitter voltage	V <sub>BE</sub>	$V_{CE} = -1 \text{ V, } I_{C} = -2 \text{ A}$	_	-0.83	-1.5	V
Transition frequency	f <sub>T</sub>	$V_{CE} = -1 \text{ V, } I_{C} = -0.5 \text{ A}$	_	140	_	MHz
Collector output capacitance	C <sub>ob</sub>	$V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$	_	50	_	pF

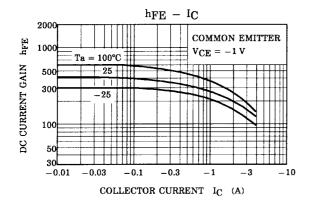
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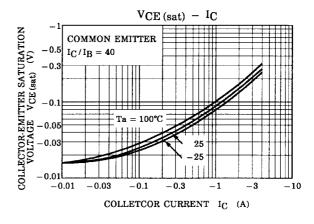
Note 2: hFE (1) classification Y: 140~280, GR: 200~400, BL: 300~600

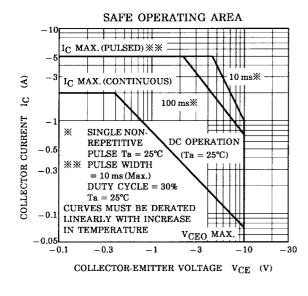
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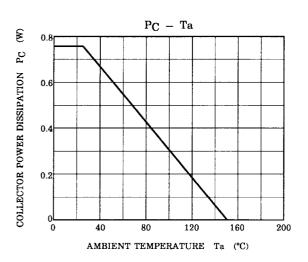












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2

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